

wherein a connection hole is provided for connecting the first conductive layer to

*cont'd*  
*b2*  
*b3*

the second conductive layer, and

wherein the connection hole extends into the semiconductor substrate, and

wherein a contact layer is provided in the connection hole.

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7. (Amended) A semiconductor device comprising:

a semiconductor substrate having a contact region provided therein;

an insulation layer provided above the semiconductor substrate; and

a semiconductor layer provided above the insulation layer, wherein the semiconductor layer includes an element isolation region which has a connection hole;

a conductive layer provided above the semiconductor layer or in the semiconductor layer, and has a function of allowing charge to flow into the semiconductor substrate, the contact region being electrically connected to the conductive layer; and

a contact layer provided in the connection hole, the contact layer electrically connecting the contact region and the conductive layer.

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